# NSN 5961-01-112-8088

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# Inclosure Material:

Plastic and metal

# **Overall Length:**

Between 0.560 inches and 0.650 inches

# **Terminal Length:**

Between 0.500 inches and 0.580 inches

# **Overall Width:**

Between 0.380 inches and 0.420 inches

### Internal Configuration:

Junction contact

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-22oab

**Mounting Method:** 

Terminal

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage, dc with specified circuit between base and emitter and 40.0 emitter to base voltage, static, collector open and 5.0 collector to base voltage/static/emitter open

### **Current Rating Per Characteristic:**

8.00 amperes source cutoff current and 0.25 amperes source cutoff current

### **Power Rating Per Characteristic:**

65.0 watts small-signal input power, common-collector preset

### Transfer Ratio:

1000.0 static forward current transfer ratio, common-emitter and 20000.0 static forward current transfer ratio, common-emitter

### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

# **Special Features:**

Junction pattern arrangement: npn

### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### **Specification Data:**

80131-release 6420 professional/industrial association specification

Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

No

### Fiig:

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